
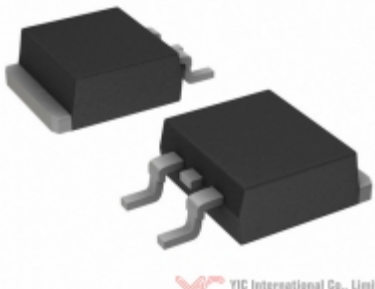








	<p>FQB22P10TM</p>
	<p>Hersteller-Teilenummer: FQB22P10TM</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 100V 22A D2PAK</p> <p>Datenblätter:  FQB22P10TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 42109 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB22P10TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 100V 22A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	42109 pcs Stock
Hersteller Standard Vorlaufzeit	15 Weeks
detaillierte Beschreibung	P-Channel 100V 22A (Tc) 3.75W (Ta), 125W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 125W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	22A (Tc)
Rds On (Max) @ Id, Vgs	125 mOhm @ 11A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	50nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQB22P10TMCT





























FQB22P10TM ist neu im Original, Suche FQB22P10TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB22P10TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB22P10TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB22P10 FAIRCHILD FQB22P10 FAIRCHILD</p>	 <p>FQB20N60LTM FS FS TO-263</p>	 <p>FQB24N08 FSC FSC TO-263</p>	 <p>FQB24N08TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 24A D2PAK</p>
 <p>FQB20N60FTM FAIRCHILD FQB20N60FTM FAIRCHILD</p>	 <p>FQB20N60TM FAIRCHILD FQB20N60TM FAIRCHILD</p>	 <p>FQB22P10TM_F085 Fairchild/ON Semiconductor FQB22P10TM_F085 Fairchild/ON Semiconductor</p>	 <p>FQB24N08TM Fairchild/ON Semiconductor MOSFET N-CH 80V 24A D2PAK</p>

heiße Teile

Mehr

 FQB16N25TM	 FQB17P06	 FQB17P10	 FQB17P10TM	 FQB17P10TM
 FQB19N10L	 FQB19N10LTM	 FQB19N10LTM	 FQB19N10TM	 FQB19N10TM
 FQB19N20	 FQB19N20C	 FQB19N20CTM	 FQB19N20CTM	 FQB19N20L
 FQB19N20LTM	 FQB19N20LTM	 FQB19N20TM	 FQB19N20TM	 FQB1N60TM
 FQB1N60TM	 FQB20N06L	 FQB20N60FTM	 FQB20N60TM	 FQB22P10
 FQB22P10TM	 FQB22P10TM_F085	 FQB24N08TM	 FQB24N08TM	 FQB25N33
 FQB25N33TM	 FQB25N33TM	 FQB25N33TM_F085	 FQB27N25TM	 FQB27P06
 FQB27P06TM	 FQB27P06TM	 FQB2N50C	 FQB2N60TM	 FQB2N60TM
 FQB2N80TM	 FQB2N80TM	 FQB2NA90TM	 FQB2NA90TM	 FQB2P25TM
 FQB2P25TM	 FQB30N06	 FQB30N06L	 FQB30N06LTM	 FQB30N06LTM

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